

QVE00033 Phototransistor Optical Surface Mount Interrupter Switch

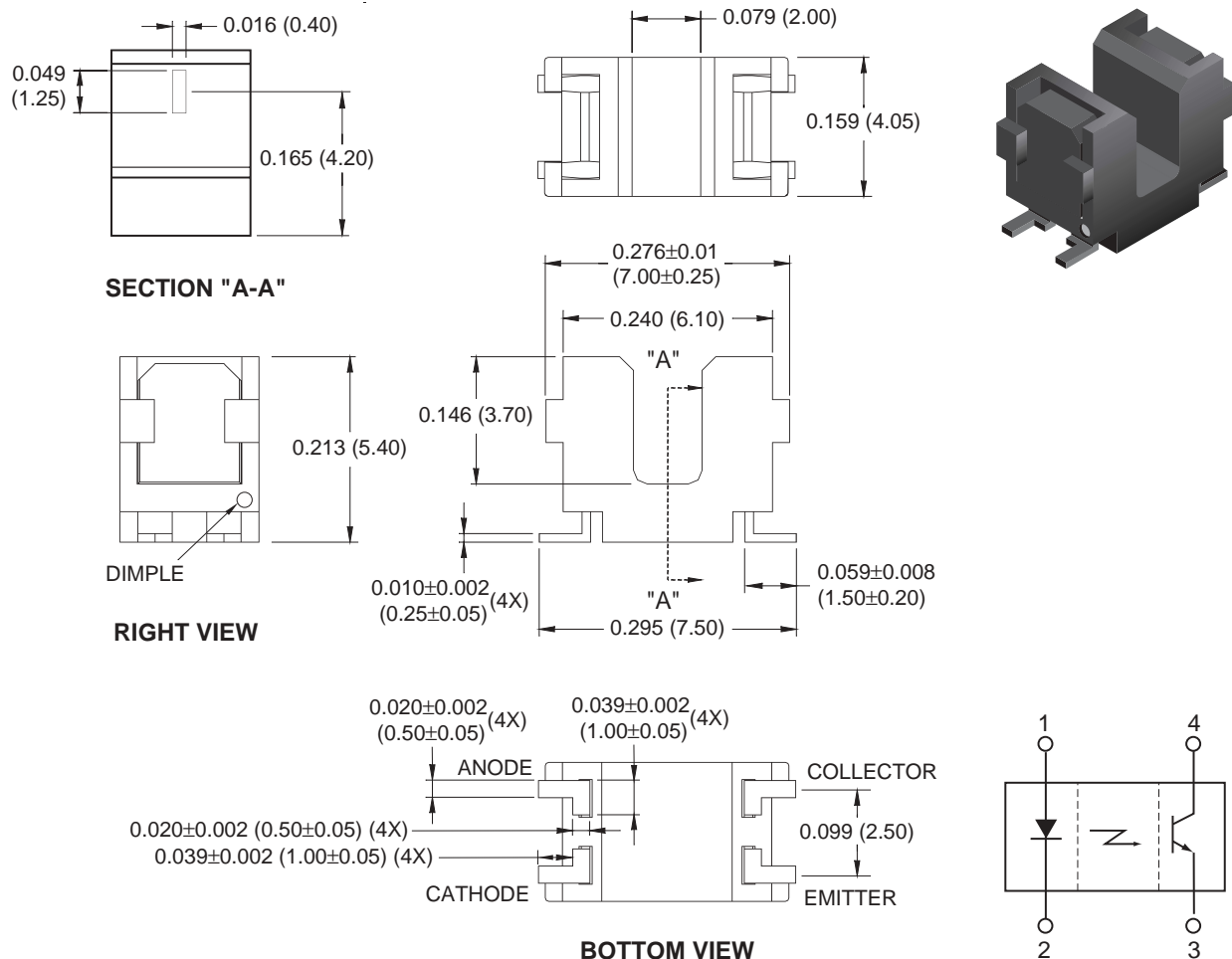
Features

- No contact switching
- Transistor Output
- Compact surface mount package
- Opaque black plastic housing
- 2mm wide slot
- 0.4 mm aperture width
- Tape and reel
- Reflow conditions:
Preheat = 160°C for 120 seconds
Reflow = 200°C for 60 seconds (peak = 240°C)
- HL-94V-0 housing

Description

The QVE00033 is a miniature slotted optical switch designed for surface mount applications. It consists of a GaAs LED and a silicon phototransistor facing each other across a 2mm gap, and packaged in a temperature resistant black plastic housing.

Package Dimension



Absolute Maximum Ratings ($T_A = 25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Rating	Units
Operating Temperature	T_{OPR}	-55 to +100	$^\circ\text{C}$
Storage Temperature	T_{STG}	-55 to +100	$^\circ\text{C}$
Soldering Temperature (Iron) ^(2,3,4)	$T_{\text{SOL-I}}$	240 for 5 sec	$^\circ\text{C}$
Soldering Temperature (Flow) ^(2,3)	$T_{\text{SOL-F}}$	260 for 10 sec	$^\circ\text{C}$
Total Power Dissipation	P_{TOT}	100	mW
Emitter			
Continuous Forward Current	I_F	50	mA
Reverse Voltage	V_R	6	V
Power Dissipation ⁽¹⁾	P_D	75	mW
Sensor			
Collector-Emitter Voltage	V_{CEO}	30	V
Emitter-Collector Voltage	V_{ECO}	4.5	V
Collector Current	I_C	20	mA
Power Dissipation ⁽¹⁾	P_D	75	mW

Electrical/Optical Characteristics ($T_A = 25^\circ\text{C}$ unless otherwise specified)

Parameter	Test Conditions	Symbol	Min.	Typ.	Max.	Units
Emitter						
Forward Voltage	$I_F = 20 \text{ mA}$	V_F	—	1.2	1.4	V
Reverse Current	$V_R = 4 \text{ V}$	I_R	—	—	10	μA
Peak Emission Wavelength	$I_F = 20 \text{ mA}$	λ_{PE}	—	940	—	nm
Sensor						
Dark Current	$V_{\text{CE}} = 20 \text{ V}, I_F = 0 \text{ mA}$	I_{CEO}	—	—	100	nA
Coupled						
Collector Current	$I_F = 5 \text{ mA}, V_{\text{CE}} = 5 \text{ V}$	$I_{\text{C(ON)}}$	100	—	600	μA
Collector Emitter	$I_F = 10 \text{ mA}, I_C = 40 \mu\text{A}$	$V_{\text{CE (SAT)}}$	—	—	0.4	V
Rise Time	$V_{\text{CC}} = 5 \text{ V}, R_L = 1000 \Omega$	t_r	—	7	150	μs
Fall Time	$I_C = 100 \mu\text{A}$	t_f	—	7	150	μs

Notes:

- Derate power dissipation linearly 1.67 mW/ $^\circ\text{C}$ above 25°C .
- RMA flux is recommended.
- Methanol or isopropyl alcohols are recommended as cleaning agents.
- Soldering iron tip 1/16" (1.6mm) from housing.

Typical Performance Characteristics

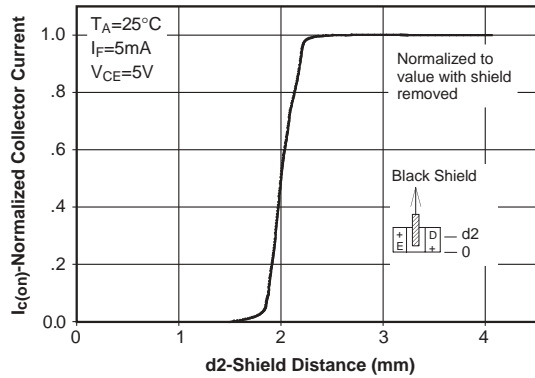


Figure 1. Normalized Collector Current Vs. Shield Distance

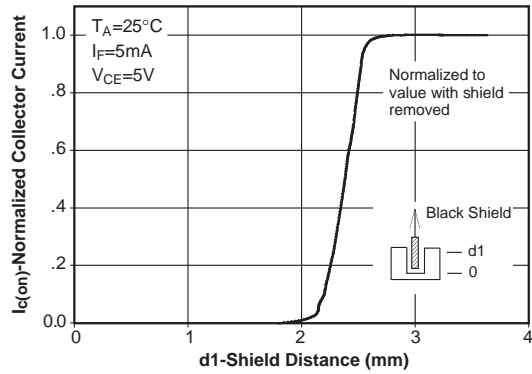


Figure 2. Normalized Collector Current Vs. Shield Distance

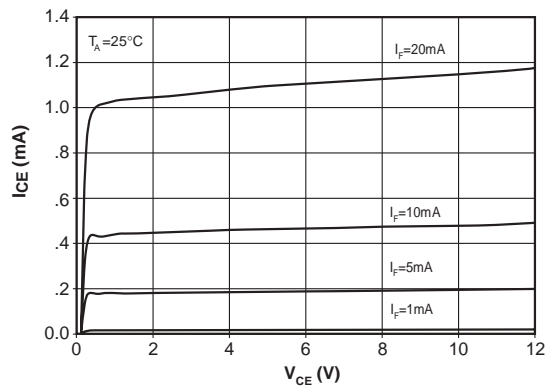


Figure 3. Collector Current Vs. Collector-Emitter Voltage

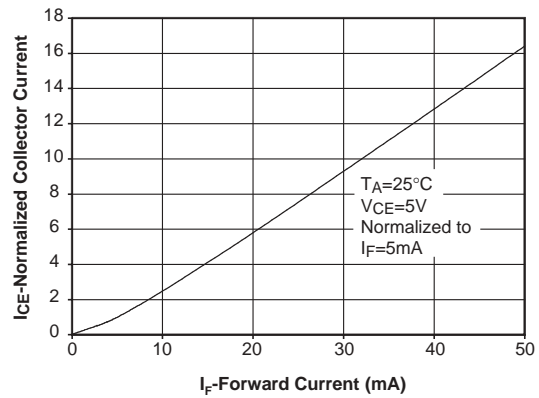


Figure 4. Normalized Collector Current Vs. Forward Current

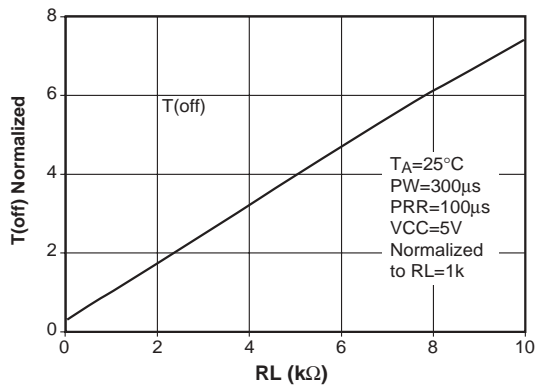


Figure 5. Rise Time vs. Load Resistance

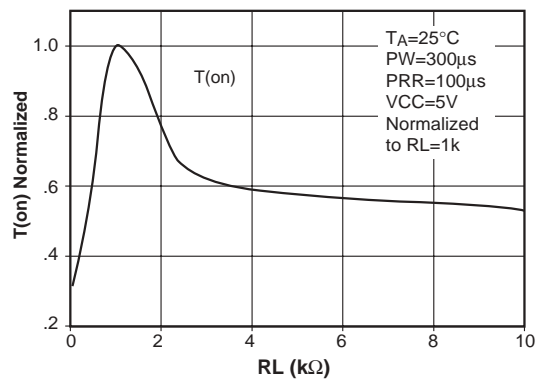
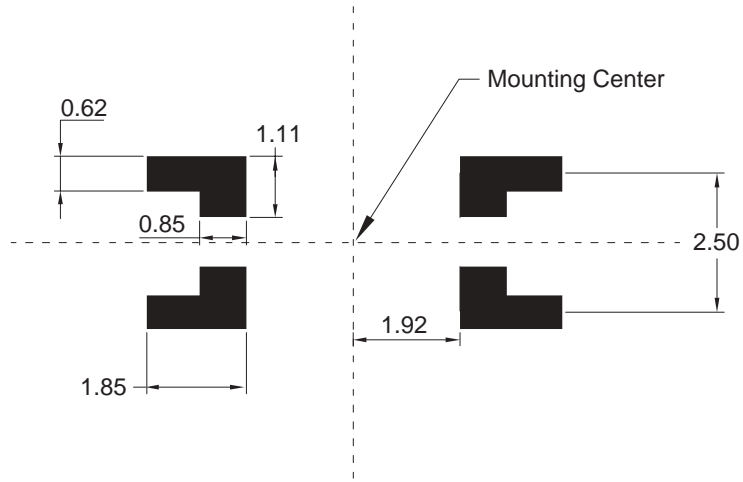
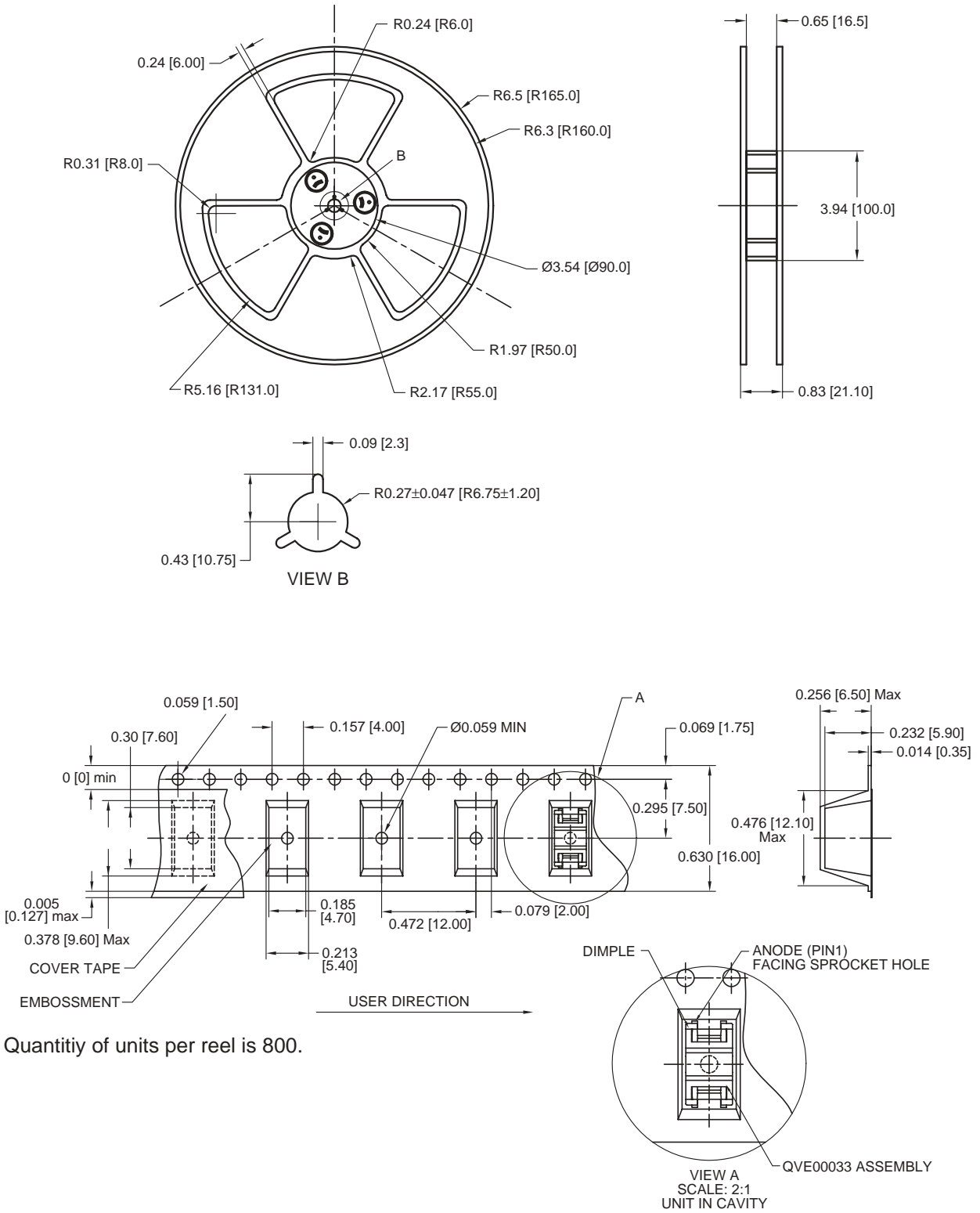


Figure 6. Fall Time vs. Load Resistance

Recommended Printed Circuit Board Pattern (For Reference Only)



Tape and Reel Dimensions



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